VS-20ETS08FP-M3, VS-20ETS12FP-M3

Vishay Semiconductors

ROHS

HALOGEN

FREE

High Voltage, Input Rectifier Diode, 20 A





TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V_R	800 V, 1200 V			
V _F at I _F	1.1 V			
I _{FSM}	300 A			
T _J max.	150 °C			
Package	TO-220 FullPAK 2L			
Circuit configuration	Single			

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS	SINGLE-PHASE BRIDGE UNITS					
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	18	22	A			

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Sinusoidal waveform	20	Α				
V _{RRM}	Range	800, 1200	V				
I _{FSM}		300	Α				
V _F	10 A, T _J = 25 °C	1.0	V				
T _J		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETS08FP-M3	800	900	4				
VS-20ETS12FP-M3	1200	1300	'				



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ABSOLUTE MAXIMUM RATINGS	S			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 51 °C, 180° conduction half sine wave	20	
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	250	Α
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300	
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-S
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	r_t $V_{F(TO)}$ $T_J = 150 ^{\circ}C$		10.4	m $Ω$
Threshold voltage	V _{F(TO)}			0.85	V
Maximum reverse leakage current	1	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA
iviaximum reverse leakage current	I _{RM}	T _J = 150 °C	v _R = nateu v _{RRM}	1.0	IIIA

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage tempera	ature range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.8	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight			0.07	OZ.	
Maurating Accessed minimum				6.0 (5.0)	kgf · cm
Mounting torque maxin	maximum			12 (10)	(lbf \cdot in)
			Coop at do TO 200 FullPAIX 21	20ETS	S08FP
Marking device			Case style TO-220 FullPAK 2L		S12FP

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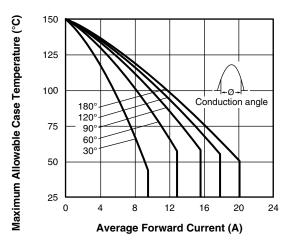


Fig. 1 - Current Rating Characteristics

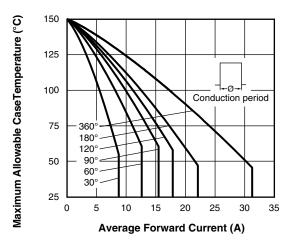


Fig. 2 - Current Rating Characteristics

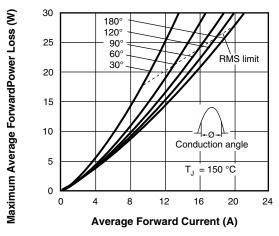


Fig. 3 - Forward Power Loss Characteristics

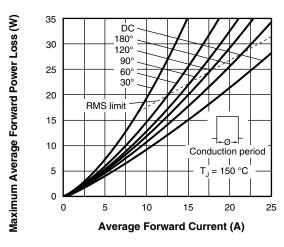


Fig. 4 - Forward Power Loss Characteristics

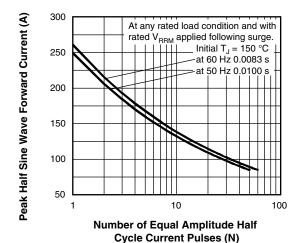


Fig. 5 - Maximum Non-Repetitive Surge Current

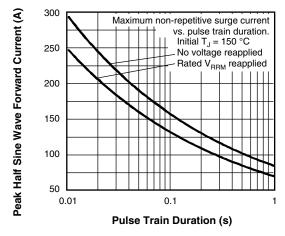


Fig. 6 - Maximum Non-Repetitive Surge Current

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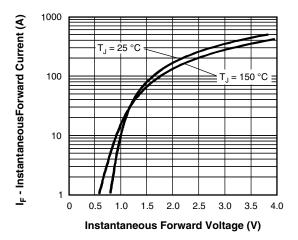


Fig. 7 - Forward Voltage Drop Characteristics

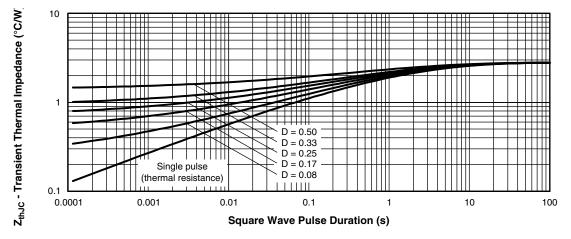


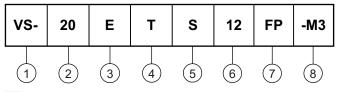
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

- Circuit configuration:

E = single diode

- Package:

T = TO-220

- Type of silicon:

S = standard recovery rectifier

Voltage ratings 08 = 800 V 12 = 1200 V

7 - FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETS08FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETS12FP-M3	50	1000	Antistatic plastic tubes		

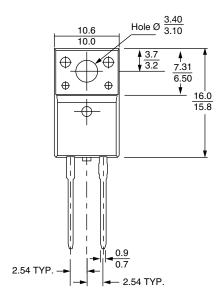
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96157</u>				
Part marking information <u>www.vishay.com/doc?95392</u>				

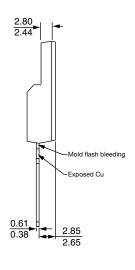


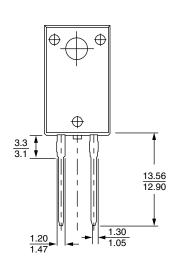
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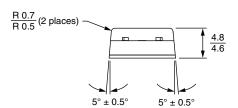
2L TO-220 FullPAK

DIMENSIONS in millimeters









Bottom view



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